



#### SLPS262-FEBRUARY 2010

## 30V N-Channel NexFET™ Power MOSFETs

Check for Samples: CSD17308Q3

## **FEATURES**

- **Optimized for 5V Gate Drive**
- Ultralow Q<sub>q</sub> and Q<sub>qd</sub>
- Low Thermal Resistance
- **Avalanche Rated**
- **Pb Free Terminal Plating**
- **RoHS Compliant**
- **Halogen Free**
- SON 3.3-mm × 3.3-mm Plastic Package

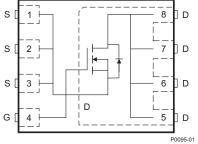
## **APPLICATIONS**

- Notebook Point of Load
- Point-of-Load Synchronous Buck in Networking, Telecom, and Computing Systems

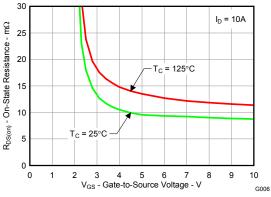
## DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications and optimized for 5V gate drive applications.









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PRODUCTION DATA information is current as of publication date

Products conform to specifications per the Instruments standard warranty. Projuctor p necessarily include testing of all paramyter.

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#### PRODUCT SUMMARY

Drain to Source Voltage	30		V
Gate Charge Total (4.5V)	3.9	nC	
Gate Charge Gate to Drain	0.8		nC
	$V_{GS} = 3V$	12.5	mΩ
Drain to Source On Resistance	$V_{GS} = 4.5V$	9.4	mΩ
	$V_{GS} = 8V$	8.2	mΩ
Threshold Voltage	1.3		V
	Drain to Source Voltage Gate Charge Total (4.5V) Gate Charge Gate to Drain Drain to Source On Resistance	$ \begin{array}{c} Gate \ Charge \ Total \ (4.5V) & 3.9 \\ \hline \\ Gate \ Charge \ Gate \ to \ Drain & 0.8 \\ \hline \\ Drain \ to \ Source \ On \ Resistance & \hline \\ V_{GS} = 3V \\ \hline \\ V_{GS} = 8V \\ \hline \end{array} $	$\begin{tabular}{ c c c c c } \hline Drain to Source Voltage & 30 \\ \hline Gate Charge Total (4.5V) & 3.9 \\ \hline Gate Charge Gate to Drain & 0.8 \\ \hline Drain to Source On Resistance & $V_{GS} = 3V$ $12.5$ \\ \hline V_{GS} = 4.5V$ $9.4$ \\ \hline V_{GS} = 8V$ $8.2$ \\ \hline \end{tabular}$

## **ORDERING INFORMATION**

Device	Package	Media	Qty	Ship
CSD17308Q3	SON 3.3-mm × 3.3-mm Plastic Package	13-Inch Reel	2500	Tape and Reel

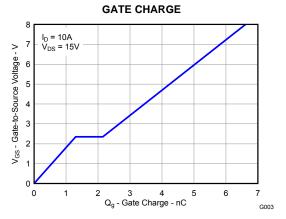
#### **ABSOLUTE MAXIMUM RATINGS**

$T_A = 2$	5°C unless otherwise stated	VALUE	UNIT
$V_{\text{DS}}$	Drain to Source Voltage	30	V
$V_{GS}$	Gate to Source Voltage	+10 /8	V
	Continuous Drain Current, $T_C = 25^{\circ}C$	47	А
ID	Continuous Drain Current <sup>(1)</sup>	13	А
I <sub>DM</sub>	Pulsed Drain Current, $T_A = 25^{\circ}C^{(2)}$	78	А
PD	Power Dissipation <sup>(1)</sup>	2.7	W
T <sub>J</sub> , T <sub>STG</sub>	Operating Junction and Storage Temperature Range	-55 to 150	ů
E <sub>AS</sub>	Avalanche Energy, single pulse I <sub>D</sub> = 36A, L = 0.1mH, R <sub>G</sub> = $25\Omega$	65	mJ

(1) Typical  $R_{\theta JA} = 46^{\circ}C/W$  on a 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>),

2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.

(2) Pulse duration ≤300µs, duty cycle ≤2%



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## **ELECTRICAL CHARACTERISTICS**

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static C	haracteristics					
BV <sub>DSS</sub>	Drain to Source Voltage	$V_{GS} = 0V, I_{D} = 250 \mu A$	30			V
I <sub>DSS</sub>	Drain to Source Leakage Current	$V_{GS} = 0V, V_{DS} = 24V$			1	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +10 / -8V$			100	nA
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.9	1.3	1.8	V
-		V <sub>GS</sub> = 3V, I <sub>D</sub> = 10A		12.5	16.5	mΩ
R <sub>DS(on)</sub>	Drain to Source On Resistance	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 10A		9.4	11.8	mΩ
		V <sub>GS</sub> = 8V, I <sub>D</sub> = 10A		8.2	10.3	mΩ
g <sub>fs</sub>	Transconductance	V <sub>DS</sub> = 15V, I <sub>D</sub> = 10A		37		S
Dynamic	c Characteristics					
C <sub>ISS</sub>	Input Capacitance			540	700	pF
C <sub>OSS</sub>	Output Capacitance	$V_{GS} = 0V, V_{DS} = 15V,$ f = 1MHz		280	365	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance	1 - 11/11/2		27	35	pF
R <sub>g</sub>	Series Gate Resistance			0.9	1.8	Ω
Qg	Gate Charge Total (4.5V)			3.9	5.1	nC
Q <sub>gd</sub>	Gate Charge Gate to Drain			0.8		nC
Q <sub>gs</sub>	Gate Charge Gate to Source	$V_{\rm DS} = 15 V, I_{\rm D} = 10 A$		1.3		nC
Qg(th)	Gate Charge at Vth			0.7		nC
Q <sub>OSS</sub>	Output Charge	$V_{DS} = 13V, V_{GS} = 0V$		7.4		nC
t <sub>d(on)</sub>	Turn On Delay Time			4.5		ns
tr	Rise Time	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 4.5V,		5.7		ns
t <sub>d(off)</sub>	Turn Off Delay Time	$I_D = 10A$ , $R_G = 2\Omega$		9.9		ns
t <sub>f</sub>	Fall Time			2.3		ns
Diode C	haracteristics		· ·		ŀ	
$V_{SD}$	Diode Forward Voltage	I <sub>DS</sub> = 10A, V <sub>GS</sub> = 0V		0.85	1	V
Q <sub>rr</sub>	Reverse Recovery Charge	$V_{DD} = 13V, I_F = 10A,$ 9.3		9.3		nC
t <sub>rr</sub>	Reverse Recovery Time	$di/dt = 300A/\mu s$		14.3		ns

## THERMAL CHARACTERISTICS

( $T_A = 25^{\circ}C$  unless otherwise stated)

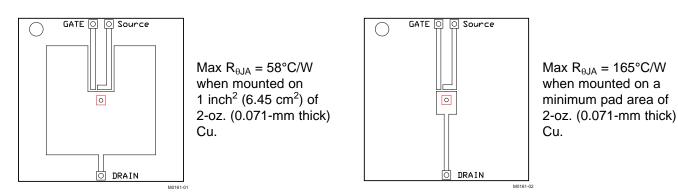
	PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case <sup>(1)</sup>			4.5	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient <sup>(1)</sup> <sup>(2)</sup>			58	°C/W

R<sub>0JC</sub> is determined with the device mounted on a 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch x 1.5-inch (3.81-cm x 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. R<sub>0JC</sub> is specified by design, whereas R<sub>0JA</sub> is determined by the user's board design.
Device mounted on FR4 material with 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu.

Pridux Filder Links): CSD17(080)



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## **TYPICAL MOSFET CHARACTERISTICS**

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

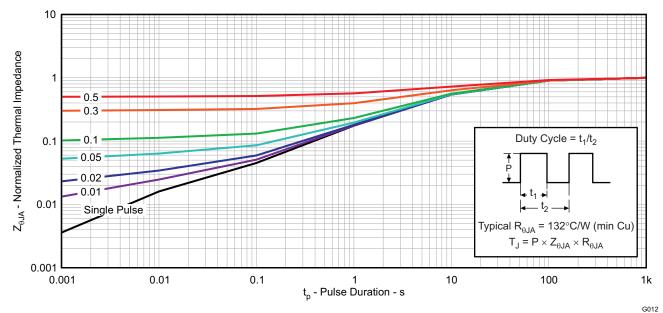


Figure 1. Transient Thermal Impedance

Pridu xt Filder Link s): CSD17(1)803

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## **TYPICAL MOSFET CHARACTERISTICS (continued)**

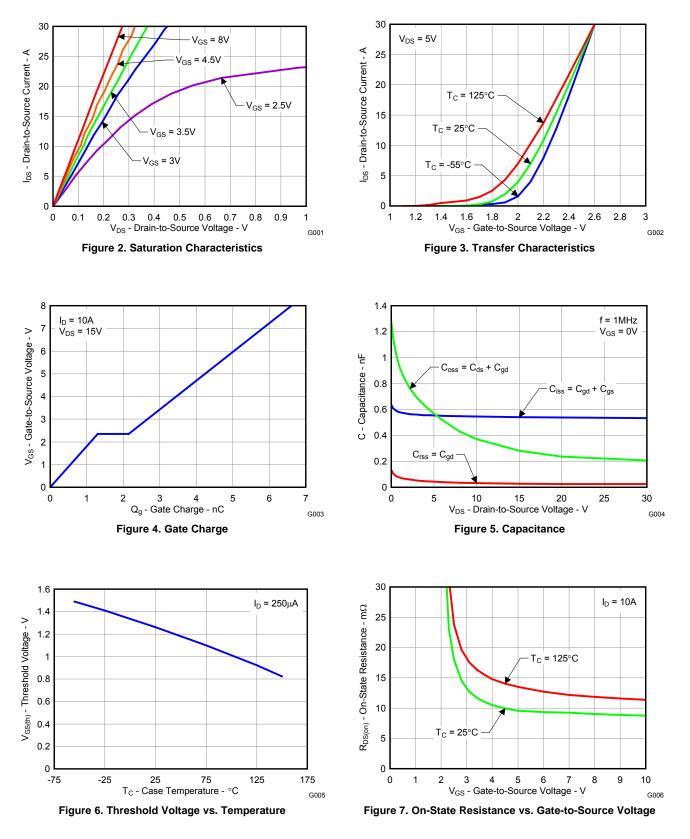
**FEXAS** 

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INSTRUMENTS

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#### $(T_A = 25^{\circ}C \text{ unless otherwise stated})$



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## CSD17308Q3

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## **TYPICAL MOSFET CHARACTERISTICS (continued)**

#### $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

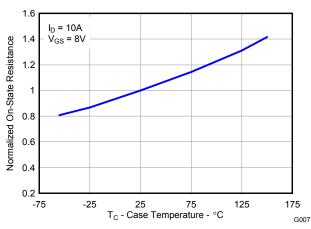


Figure 8. Normalized On-State Resistance vs. Temperature

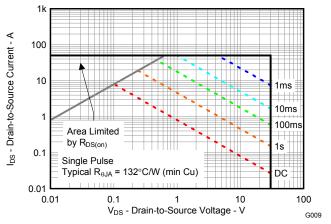


Figure 10. Maximum Safe Operating Area

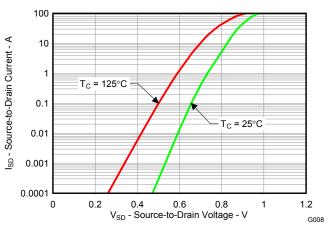


Figure 9. Typical Diode Forward Voltage

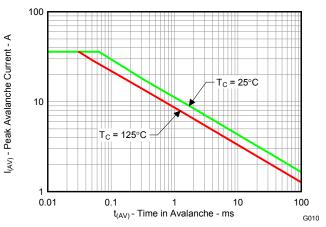
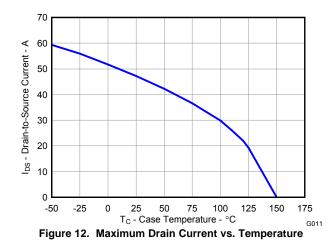


Figure 11. Single Pulse Unclamped Inductive Switching



Priduct Folder Link s). CSD173080

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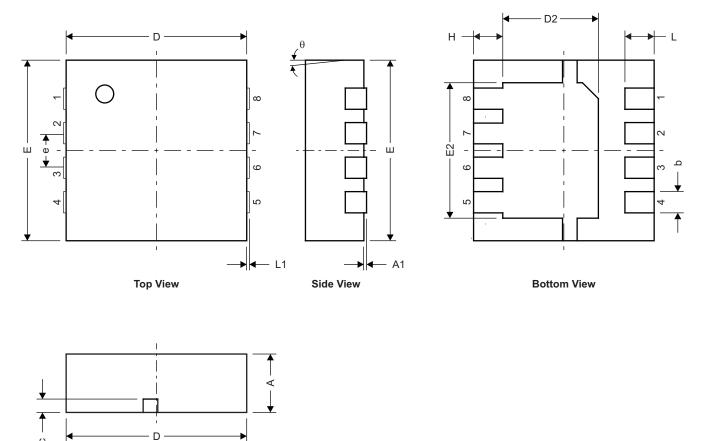
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## **MECHANICAL DATA**

## Q3 Package Dimensions



M0142-01

DIM		MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX		
А	0.950	1.000	1.100	0.037	0.039	0.043		
A1	0.000	0.000	0.050	0.000	0.000	0.002		
b	0.280	0.340	0.400	0.011	0.013	0.016		
С	0.150	0.200	0.250	0.006	0.008	0.010		
D	3.200	3.300	3.400	0.126	0.130	0.134		
D1	-	_	_	_	_	_		
D2	1.650	1.750	1.800	0.065	0.069	0.071		
E	3.200	3.300	3.400	0.126	0.130	0.134		
E1	-	-	-	-	-	-		
E2	2.350	2.450	2.550	0.093	0.096	0.100		
е		0.650 TYP	•		0.026	•		
Н	0.35	0.450	0.550	0.014	0.018	0.022		
L	0.35	0.450	0.550	0.014	0.018	0.022		
L1	-	-	-	_	-	-		
θ	-	-	-	-	-	-		

Priduct Folder Link s). CSD173.080

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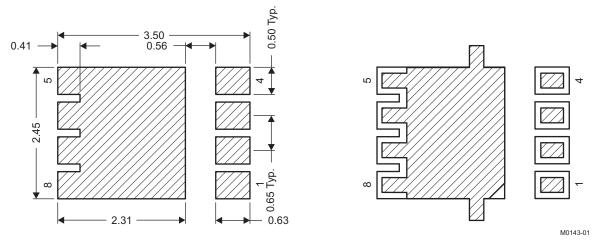
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**Front View** 

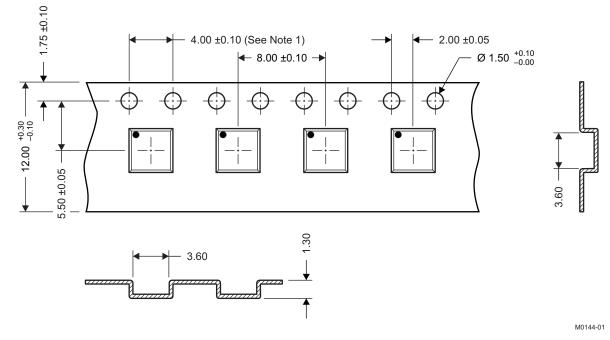


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## **Recommended PCB Pattern**



For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.



Priduct Filder Links).

CSD173 08C 3

## **Q3 Tape and Reel Information**

### Notes:

- 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. Thickness: 0.30 ±0.05mm
- 6. MSL1 260°C (IR and convection) PbF reflow compatible

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## **Package Marking Information**

Location	0	_	-	0
1st Line	8	5	5	8
CSD = Fixed Characters			1.1	1 ( ) ( ) ( ) ( ) ( ) ( ) ( ) ( ) ( ) (
NNNNN = Product Code				
2nd Line (Date Code)	CSDNI	NNNN		
YY = Last 2 digits of the Year				
WW = 2-digit Work Week	YYWW			
C = Country of Origin	LLLLL			
> Philippines = P				
> Taiwan = T				
> China = C				
3rd Line	1	4	4	1
LLLLL = Last 5 digits of the Wafer Lot	# Pin 1 Identifier			

M0145-01

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## **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins Pa	ackage Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
CSD17308Q3	ACTIVE	SON	DQG	8	2500	Pb-Free (RoHS Exempt)	Call TI	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

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Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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